Quantum Sensing and Nanophotonic Devices VIII

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Keynote Session
Manijeh Razeghi, Northwestern University (United States)

1 Quantum Cascade Lasers and Applications I
Armin Lambrecht, Fraunhofer-Institut für Physikalische Messtechnik (Germany)
Manijeh Razeghi, Northwestern University (United States)

2 Quantum Cascade Lasers and Applications II
Alexei N. Baranov, Université Montpellier 2 (France)
Shigeyuki Kuboya, The University of Tokyo (Japan)

3 Quantum Cascade Lasers and Applications III
Jerry R. Meyer, U.S. Naval Research Laboratory (United States)
Miriam S. Vitiello, Università degli Studi di Bari (Italy)

4 Quantum Cascade Lasers and Applications IV
Jean-Pierre Huignard, Thales Research & Technology (France)
Sheng Wu, California Institute of Technology (United States)

5 Terahertz and Plasmonics Devices I
Nicolas Péré-Laperne, Centre National de la Recherche Scientifique (France)
In-Hwan Lee, Chonbuk National University (Korea, Republic of)

6 Terahertz and Plasmonics Devices II
Mauro Fernandes Pereira, Jr., Sheffield Hallam University (United Kingdom)
Vincenzo Spagnolo, Politecnico di Bari (Italy)
7 Thin Films Nitrides I
Woo-Gwang Jung, Kookmin University (Korea, Republic of)
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8 Thin Films Nitrides II
Kentaro Onabe, The University of Tokyo (Japan)
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9 Detectors and Imaging I
Meimei Z. Tidrow, U.S. Army Night Vision & Electronic Sensors
   Directorate (United States)
Marija Strojnik, Centro de Investigaciones en Óptica, A.C. (Mexico)

10 Detectors and Imaging II
David A. Cardimona, Air Force Research Laboratory (United States)
Jung Han, Yale University (United States)

11 Detectors and Imaging III
John E. Hubbs, Ball Aerospace & Technologies Corporation (United States)
Mahmoud Fallahi, College of Optical Sciences, The University of Arizona (United States)

12 Detectors and Imaging IV
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13 Nanophotonic Devices I
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14 Nanophotonic Devices II
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15 Nanophotonic Devices III
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Mark A. Itzler, Princeton Lightwave, Inc. (United States)
Melville P. Ulmer, Northwestern University (United States)